

Photocouplers GaAlAs Infrared LED & Photo IC

TLP2309

1. Applications

- · Transistor Inverters
- · Switching Power Supplies
- · High-Speed Digital Interfacing

2. General

The Toshiba TLP2309 consists of a high-output GaAlAs light-emitting diode coupled with a high-speed photo-diode-transistor chip. It is housed in the SO6 package. The TLP2309 guarantees operation at up to 110 °C and on supplies both 3.3 V and 5 V. Also, since the TLP2309 guarantees a creepage / clearance distance \geq 5.0 mm and internal isolation thickness \geq 0.4 mm, this product is in the reinforced insulation class according to international safety standards.

3. Features

- (1) Inverter logic type (open collector output)
- (2) Package: SO6
- (3) Operating temperature: -40 to 110 °C
- (4) Supply voltage: 3.3 V / 5 V
- (5) Data transfer rate: 1 Mbit/s (typ.) (NRZ)
- (6) Common-mode transient immunity: 15 kV/μs (min)
- (7) Isolation voltage: 3750 Vrms (min)
- (8) Safety standards

UL-approved: UL1577, File No.E67349

cUL-approved: CSA Component Acceptance Service No.5A File No.E67349

VDE-approved: EN60747-5-5 (Note 1)

CQC-approved: GB4943.1, GB8898 Thailand Factory

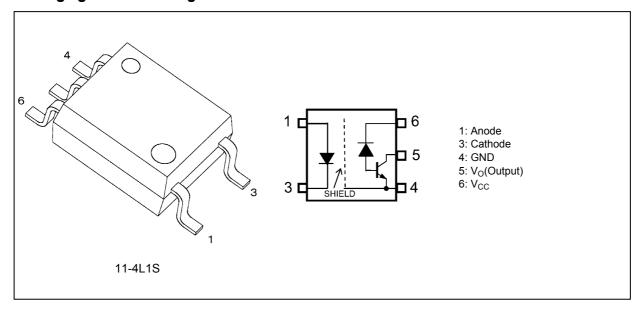


仅适用干海拔 2000m 以下地区安全使用

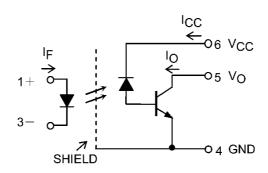
Note 1: When an EN60747-5-5 approved type is needed, please designate the Option (V4).



4. Packaging and Pin Configuration



5. Internal Circuit



6. Principle of Operation

6.1. Truth Table

Input	LED	Output
Н	ON	L
L	OFF	Н

6.2. Mechanical Parameters

Characteristics	Min	Unit
Creepage distances	5.0	mm
Clearance distances	5.0	
Internal isolation thickness	0.4	



7. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

	Characteristics		Symbol	Note	Rating	Unit
LED	Input forward current		I _F		25	mA
	Input forward current derating	(T _a ≥ 100 °C)	$\Delta I_F/\Delta T_a$		-1.0	mA/°C
	Input forward current (pulsed)		I _{FP}	(Note 1)	50	mA
	Input forward current derating (pulsed)	$(T_a \ge 100 ^{\circ}\text{C})$	$\Delta I_{FP}/\Delta T_a$		-2.0	mA/°C
	Peak transient input forward current		I _{FPT}	(Note 2)	1	A
	Peak transient input forward current derating	$(T_a \ge 85 ^{\circ}C)$	$\Delta I_{FPT}/\Delta T_a$		-25	mA/°C
	Input power dissipation		P _D		40	mW
	Input power dissipation derating	$(T_a \ge 100 ^{\circ}\text{C})$	$\Delta P_D/\Delta T_a$		-1.6	mW/°C
	Input reverse voltage		V _R		5	V
Detector	Output current		Io		8	mA
	Peak output current		I _{OP}		16	
	Supply voltage		V _{CC}		-0.5 to 30	V
	Output voltage		Vo		-0.5 to 20	
	Output power dissipation		Po		100	mW
	Output power dissipation derating	(T _a ≥ 100 °C)	$\Delta P_{O}/\Delta T_{a}$		-4.0	mW/°C
Common	Operating temperature		T _{opr}		-40 to 110	°C
	Storage temperature		T _{stg}		-55 to 125	
	Lead soldering temperature	(10 s)	T _{sol}		260	
	Isolation voltage	AC, 60 s, R.H. ≤ 60 %	BV _S	(Note 3)	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Pulse width (PW) \leq 1 ms, duty = 50 %
- Note 2: Pulse width (PW) \leq 1 μ s, 300 pps
- Note 3: This device is considered as a two-terminal device: Pins 1 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.

8. Recommended Operating Conditions (Note)

Characteristics	Symbol	Note	Min	Тур.	Max	Unit
Input on-state current	I _{F(ON)}		10	_	20	mA
Input off-state voltage	V _{F(OFF)}		0	_	0.8	V
Supply voltage	V _{CC}		2.7	3.3 / 5	20	
Operating temperature	T _{opr}	(Note 1)	-40	_	110	°C

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this datasheet should also be considered.

Note: A ceramic capacitor $(0.1 \, \mu F)$ should be connected between pin 6 and pin 4 to stabilize the operation. Otherwise, this photocoupler may not switch properly. The bypass capacitor should be placed within 1 cm of each pin.

Note 1: Denotes the operating range, not the recommended operating condition.



9. Electrical Characteristics (Note) (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input forward voltage	V_{F}	I _F = 10 mA	1.45	1.55	1.7	V
Input forward voltage temperature coefficient	$\Delta V_F/\Delta T_a$	I_F = 10 mA, T_a = -40 °C to 110 °C	_	-2.0	_	mV/°C
Input reverse current	I _R	V _R = 5 V	_	_	10	μА
Input capacitance	Ct	V = 0 V, f = 1 MHz	_	60	_	pF
High-level output current	I _{OH}	$I_F = 0 \text{ mA}, V_O = 5.5 \text{ V}, V_{CC} = 5.5 \text{ V}$	_	3	500	nA
		$I_F = 0 \text{ mA}, V_O = 20 \text{ V}, V_{CC} = 30 \text{ V}$	_	_	5	μА
		$I_F = 0 \text{ mA}, V_O = 20 \text{ V}, V_{CC} = 30 \text{ V},$ $T_a = 110 ^{\circ}\text{C}$	_	_	50	
High-level supply current	Іссн	I _F = 0 mA, V _{CC} = 30 V	_	0.01	1	
Current transfer ratio	I _O /I _F	I _F = 10 mA, V _O = 0.4 V, V _{CC} = 3.3 V	15	_	_	%
		I _F = 16 mA, V _O = 0.4 V, V _{CC} = 4.5 V	15	_	_	
Low-level output voltage	V _{OL}	I _F = 16 mA, V _{CC} = 4.5 V, I _O = 2.4 mA	_	_	0.4	V

Note: All typical values are at $T_a = 25$ °C.

10. Isolation Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Test Conditions	Min	Тур.	Max	Unit
Total capacitance (input to output)	C _S	(Note 1)	V _S = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R _S	(Note 1)	V _S = 500 V, R.H. ≤ 60 %	1 × 10 ¹²	1014		Ω
Isolation voltage	BV _S		AC, 60 s	3750	_		Vrms
			AC, 1 s in oil	_	10000	_	
			DC, 60 s in oil	_	10000	_	Vdc

Note 1: This device is considered as a two-terminal device: Pins 1 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.

11. Switching Characteristics (Note) (Unless otherwise specified, T_a = -40 to 110 °C)

Characteristics	Symbol	Note	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Propagation delay time (H/L)	t _{pHL}			I_F = 0 \rightarrow 10 mA, R_L = 1.9 k Ω , V_{CC} = 3.3 V, C_L = 15 pF	_		1	μS
Propagation delay time (L/H)	t _{pLH}			I_F = 10 \rightarrow 0 mA, R_L = 1.9 k Ω , V_{CC} = 3.3 V, C_L = 15 pF			1	
Propagation delay time (H/L)	t _{pHL}			I_F = 0 \rightarrow 16 mA, R_L = 1.9 kΩ, V_{CC} = 5 V, C_L = 15 pF	ı	ı	0.8	
Propagation delay time (L/H)	t _{pLH}			I_F = 16→0 mA, R_L = 1.9 kΩ, V_{CC} = 5 V, C_L = 15 pF	_		0.8	
Common-mode transient immunity at output high	CM _H	(Note 1)		$\begin{split} I_F &= 0 \text{ mA, V}_{CC} = 3.3 \text{ V } / 5 \text{ V,} \\ V_{CM} &= 400 \text{ V}_{p\text{-}p}, \text{ R}_L = 4.1 \text{ k}\Omega, \\ T_a &= 25 ^\circ\text{C} \end{split}$	15	20		kV/μs
Common-mode transient immunity at output low	CM _L	(Note 1)		$\begin{split} I_F &= 10 \text{ mA}, V_{CC} = 3.3 \text{ V} / 5 \text{ V}, \\ V_{CM} &= 400 V_{p\text{-}p}, R_L = 4.1 \text{ k}\Omega, \\ T_a &= 25 ^{\circ}\text{C} \end{split}$	-15	-20		

Note: All typical values are at $T_a = 25$ °C.

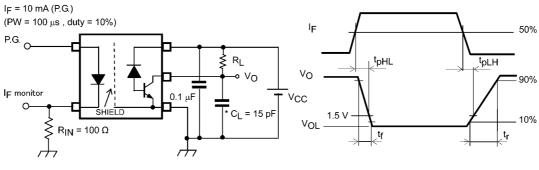
Note 1: CM_H is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic high state ($V_O > 2.0 \text{ V}$).

 CM_L is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic low state ($V_O < 0.8 \text{ V}$).



12. Test Circuits and Characteristics Curves

12.1. Test Circuits



*C_L includes probe and stray capacitance.

P.G.: Pulse generator

Fig. 12.1.1 Switching Time Test Circuit

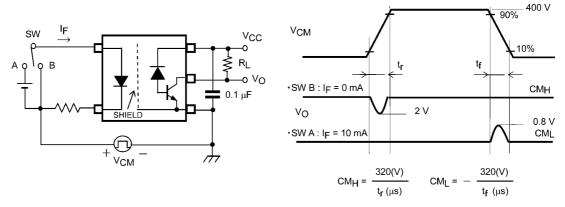
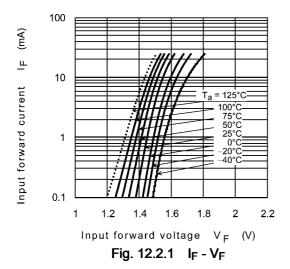
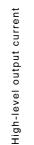


Fig. 12.1.2 Common-Mode Transient Immunity



12.2. Characteristics Curves (Note)





(nA)

HOH

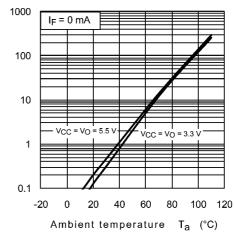


Fig. 12.2.2 I_{OH} - T_a

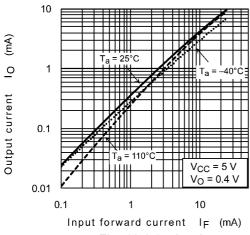


Fig. 12.2.3 I_O - I_F

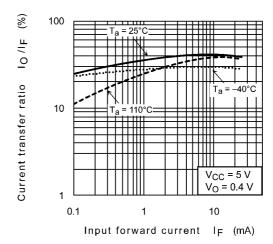
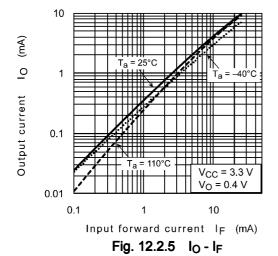


Fig. 12.2.4 I_O/I_F - I_F



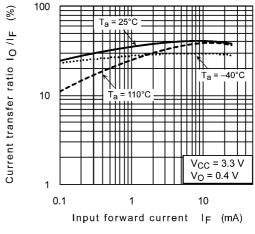
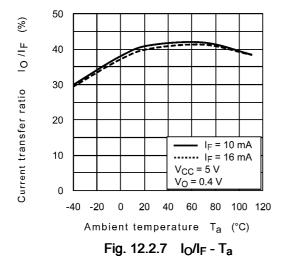
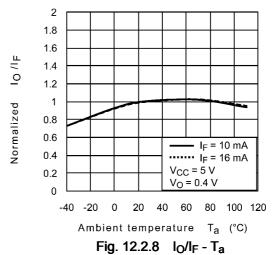
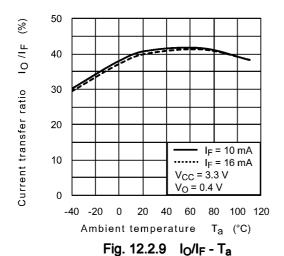
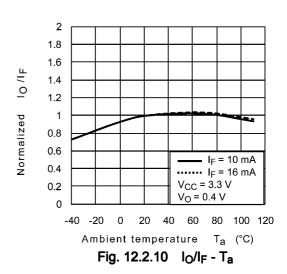


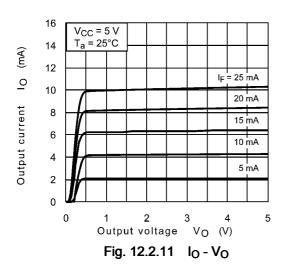
Fig. 12.2.6 I_O/I_F - I_F

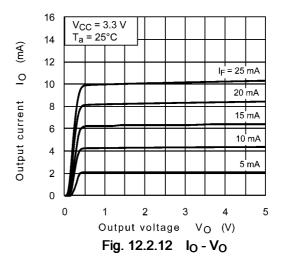












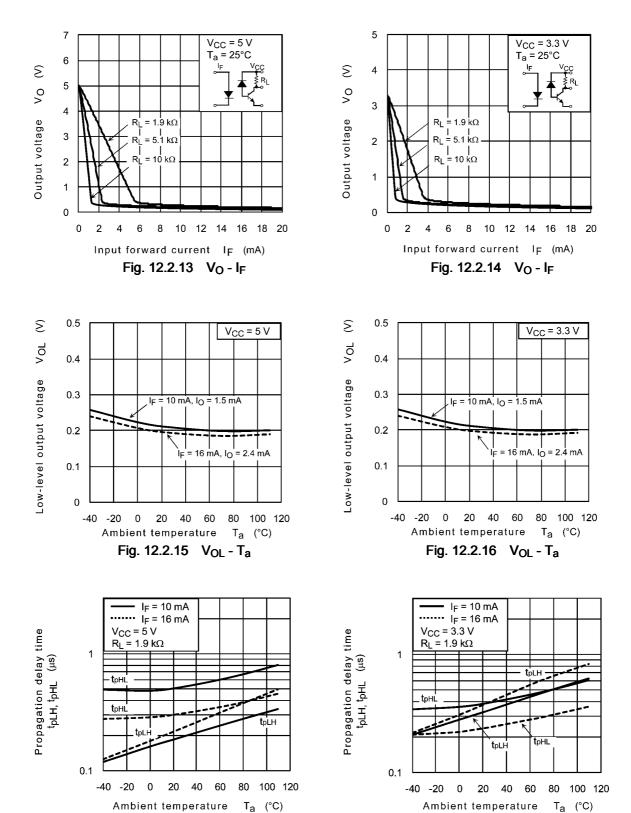
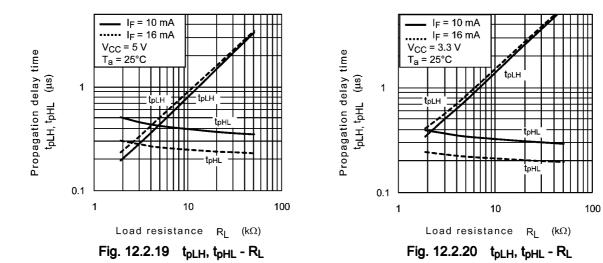


Fig. 12.2.17 t_{pLH} , t_{pHL} - T_a

Fig. 12.2.18 t_{pLH} , t_{pHL} - T_{ap}



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



13. Soldering and Storage

13.1. Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

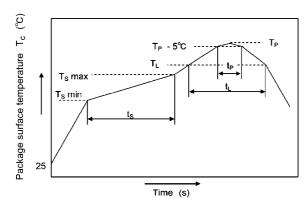
· When using soldering reflow.

The soldering temperature profile is based on the package surface temperature.

(See the figure shown below, which is based on the package surface temperature.)

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.



	Symbol	Min	Max	Unit
Preheat temperature	Ts	150	200	°C
Preheat time	ts	60	120	s
Ramp-up rate (T _L to T _P)			3	°C/s
Liquidus temperature	TL	217		°C
Time above T _L	tL	60	150	s
Peak temperature	T _P		260	°C
Time during which T_c is between $(T_P - 5)$ and T_P	t _P		30	s
Ramp-down rate (T _P to T _L)			6	°C/s

Fig. 13.1.1 An example of a temperature profile when lead(Pb)-free solder is used

· When using soldering flow

Preheat the device at a temperature of 150 °C (package surface temperature) for 60 to 120 seconds.

Mounting condition of 260 $^{\circ}\text{C}$ within 10 seconds is recommended.

Flow soldering must be performed once.

· When using soldering Iron

Complete soldering within 10 seconds for lead temperature not exceeding 260 °C or within 3 seconds not exceeding 350 °C

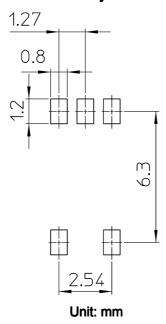
Heating by soldering iron must be done only once per lead.

13.2. Precautions for General Storage

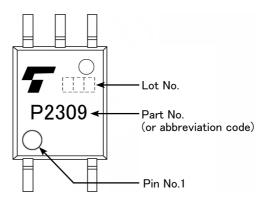
- Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- Follow the precautions printed on the packing label of the device for transportation and storage.
- Keep the storage location temperature and humidity within a range of 5 °C to 35 °C and 45 % to 75 %, respectively.
- Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- · When restoring devices after removal from their packing, use anti-static containers.
- · Do not allow loads to be applied directly to devices while they are in storage.
- If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.



14. Land Pattern Dimensions for Reference Only



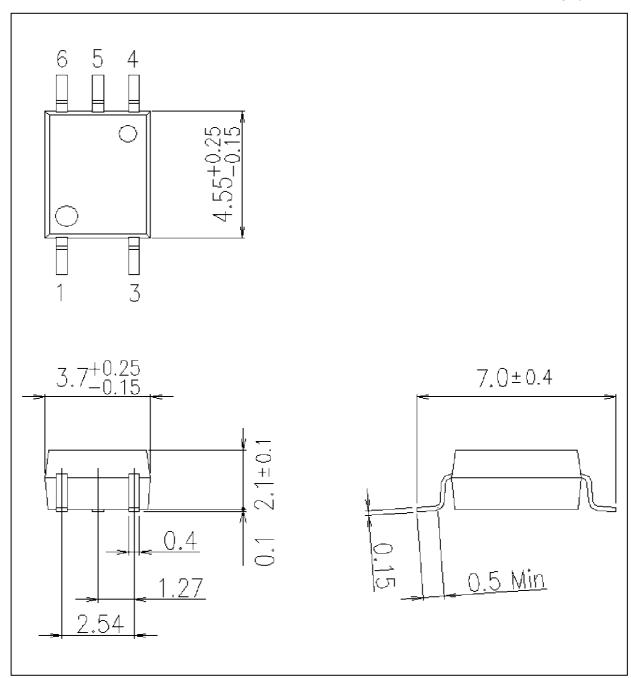
15. Marking





Package Dimensions

Unit: mm



Weight: 0.08 g (typ.)

	Package Name(s)
TOSHIBA: 11-4L1S	

Rev.7.0



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